

LINEAR INTEGRATED CIRCUITS



LS107
LS207
LS307

FREQUENCY COMPENSATED OPERATIONAL AMPLIFIERS

- LOW OFFSET CURRENT AND VOLTAGE
- LOW INPUT CURRENT
- GUARANTEED DRIFT CHARACTERISTICS

The LS 107 series consists of general purpose operational amplifiers, with the frequency compensation built into the chip. They replace pin-to-pin the LS 709, LS 101, LS 141 and LS 148.

The LS 107 series offers features similar to the LS 101A, providing better accuracy and lower noise in high impedance circuits. The low input currents allow the device to be used in slow charge applications, such as long interval integrators, slow ramps, sample and hold circuits.

The LS 107 series is available with hermetic gold chip (8000 series), particularly suitable for professional and telecom applications, wherever very high MTBF are required.

ABSOLUTE MAXIMUM RATINGS

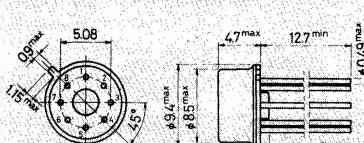
		TO-99	Minidip	μ package
V_s	Supply voltage for LS 107 and LS 207 for LS 307		$\pm 22V$ $\pm 18V$ $\pm 15V$ $\pm 30V$	
V_i (1)	Input voltage		-55 to 125 °C	
ΔV_i	Differential input voltage		-25 to 85 °C	
T_{op}	Operating temperature for LS 107 for LS 207 for LS 307		0 to 70 °C indefinite	
P_{tot}	Output short circuit duration (2)	520 mW	665 mW	400 mW
T_{stg}	Power dissipation at $T_{amb} = 70$ °C	-65 to 150 °C	-55 to 150 °C	-55 to 150 °C
	Storage temperature	300 °C (10s)	260 °C (12s)	260 °C (5s)
	Lead soldering temperature			235 °C (11s)

1) For supply voltages less than ± 15 V, input voltage is equal to the supply voltage

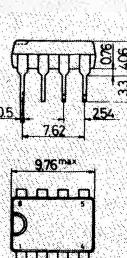
2) The short circuit duration is limited by thermal dissipation

MECHANICAL DATA

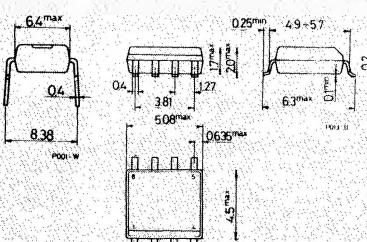
Dimensions in mm



TO-99



Minidip

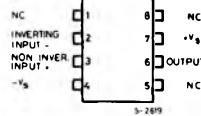
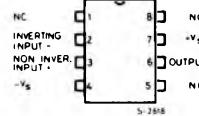
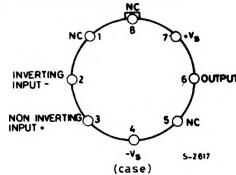


SO-8

SSS

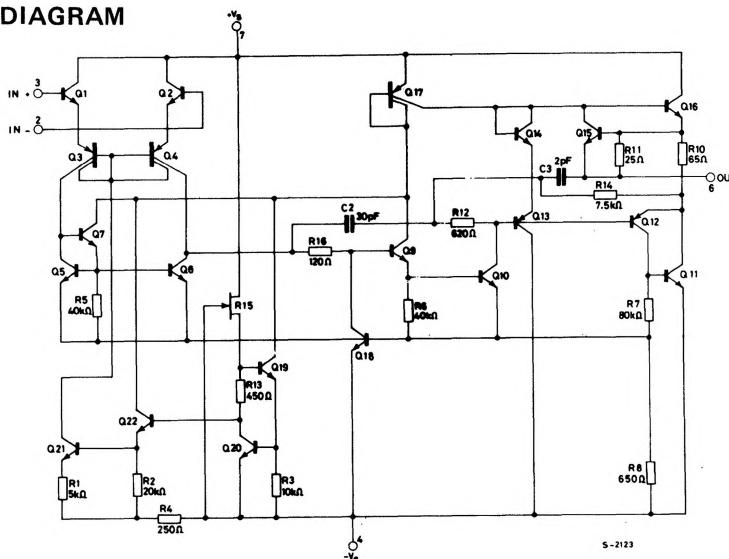
LS107
LS207
LS307

CONNECTION DIAGRAMS AND ORDERING NUMBERS (top views)



Type	TO-99	Minidip	SO-8
LS 107	LS 107T	—	—
LS 207	LS 207T	—	—
LS 307	LS 307T	LS 307B	LS 307M
LS 8107	—	—	LS 8107M
LS 8207	—	—	LS 8207M
LS 8307	—	—	LS 8307M

SCHEMATIC DIAGRAM



THERMAL DATA

	TO-99	Minidip	SO-8	
R _{th} j-amb Thermal resistance junction-ambient	max	155 °C/W	120 °C/W	200* °C/W

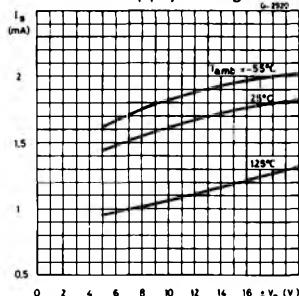
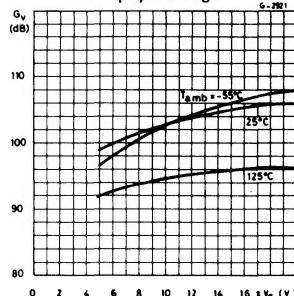
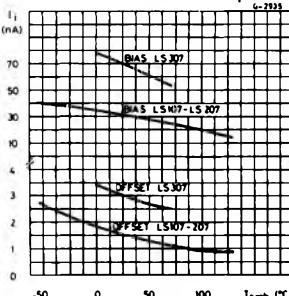
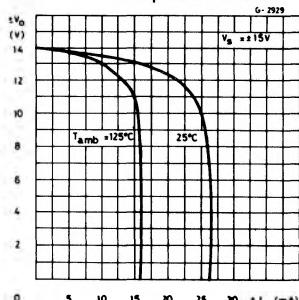
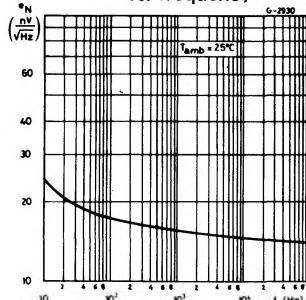
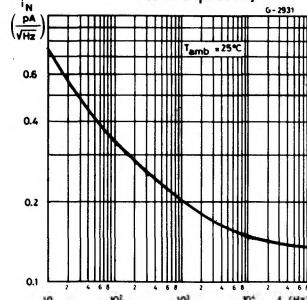
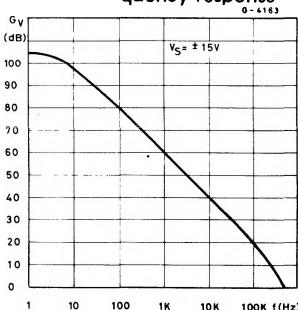
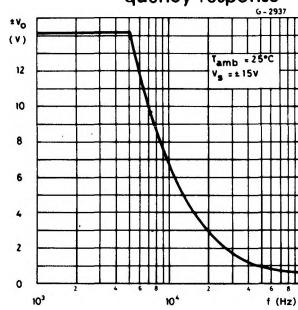
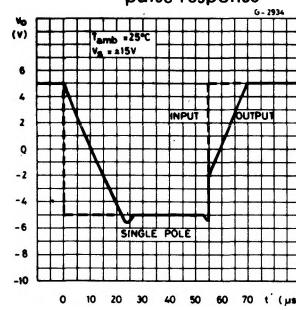
* Measured with the device mounted on a ceramic substrate (25x16x0.6 mm)



ELECTRICAL CHARACTERISTICS (see note)

Parameter	Test conditions	LS 107/LS 207			LS 307			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V_{os}	Input offset voltage $R_g \leq 10 \text{ k}\Omega$ $R_g \leq 10 \text{ k}\Omega \quad T_{amb} = 25^\circ\text{C}$		0.7	3 2		2	10 7.5	mV mV
$\frac{\Delta V_{os}}{\Delta T}$	Average temperature coefficient of input offset voltage		3	15		6	30	$\mu\text{V}/^\circ\text{C}$
I_{os}	Input offset current $T_{amb} = 25^\circ\text{C}$		1.5	20 10		3	70 50	nA nA
$\frac{\Delta I_{os}}{\Delta T}$	Average temperature coefficient of input offset current $T_{amb} = 25^\circ\text{C} \text{ to } T_{max}$ $T_{amb} = T_{min} \text{ to } 25^\circ\text{C}$		0.01 0.02	0.1 0.2		0.01 0.02	0.3 0.6	nA/ $^\circ\text{C}$ nA/ $^\circ\text{C}$
I_b	Input bias current $T_{amb} = 25^\circ\text{C}$		30	100 75		70	300 250	nA nA
R_i	Input resistance $T_{amb} = 25^\circ\text{C}$	1.5	4		0.5	2		M Ω
G_v	Large signal voltage gain $V_s = \pm 15\text{V}$ $R_L \geq 2 \text{ k}\Omega$	88			84			dB
	$V_s = \pm 15\text{V}$ $R_L \geq 2 \text{ k}\Omega \quad T_{amb} = 25^\circ\text{C}$	94	104		88	104		dB
V_i	Input voltage range $V_s = \pm 20\text{V}$ $V_s = \pm 15\text{V}$	± 15			± 12			V V
V_o	Output voltage swing $V_s = \pm 15\text{V} \quad R_L = 10 \text{ k}\Omega$ $V_s = \pm 15\text{V} \quad R_L = 2 \text{ k}\Omega$	± 12 ± 10	± 14 ± 13		± 12 ± 10	± 14 ± 13		V V
CMR	Common mode rejection $R_g \leq 10 \text{ k}\Omega$	80	96		70	90		dB
SVR	Supply voltage rejection $R_g \leq 10 \text{ k}\Omega$	80	96		70	96		dB
I_s	Supply current $V_s = \pm 20\text{V}$ $T_{amb} = 25^\circ\text{C}$ $T_{amb} = 125^\circ\text{C}$ $V_s = \pm 15\text{V} \quad T_{amb} = 25^\circ\text{C}$		1.8 1.2	3 2.5			1.8 3	mA mA mA

Note: These specifications, unless otherwise specified, apply for $V_s = \pm 5\text{V}$ to $\pm 20\text{V}$ and $T_{amb} = -55$ to 125°C for LS 107; $V_s = \pm 5\text{V}$ to $\pm 20\text{V}$ and $T_{amb} = -25$ to 85°C for LS 207; $V_s = \pm 5\text{V}$ to $\pm 15\text{V}$ and $T_{amb} = 0$ to 70°C for LS 307.

SSS**LS107**
LS207
LS307**Fig. 1 - Supply current vs. supply voltage****Fig. 2 - Voltage gain vs. supply voltage****Fig. 3 - Input current vs. ambient temp.****Fig. 4 - Current limiting vs. output current****Fig. 5 - Input noise voltage vs. frequency****Fig. 6 - Input noise current vs. frequency****Fig. 7 - Open loop frequency response****Fig. 8 - Large signal frequency response****Fig. 9 - Voltage follower pulse response**



**LS107
LS207
LS307**

Guaranteed performance characteristics (LS 107/LS 207)

Fig. 10 - Input voltage range vs. supply voltage

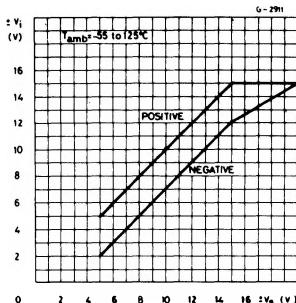


Fig. 11 - Output voltage swing vs. supply voltage

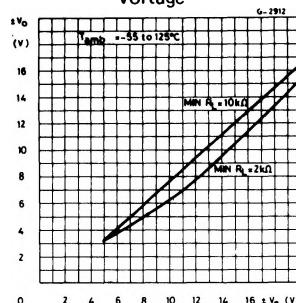
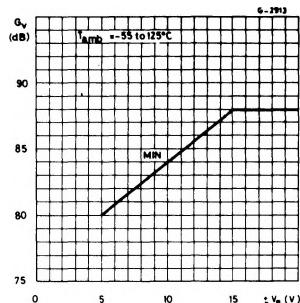


Fig. 12 - Voltage gain vs. supply voltage



Guaranteed performance characteristics (LS 307)

Fig. 13 - Input voltage range vs. supply voltage

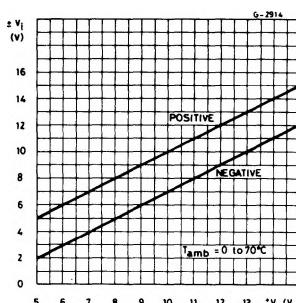


Fig. 14 - Output voltage swing vs. supply voltage

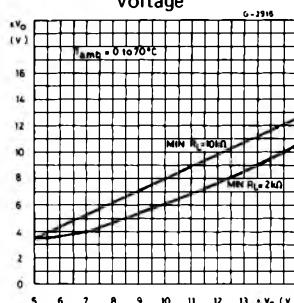
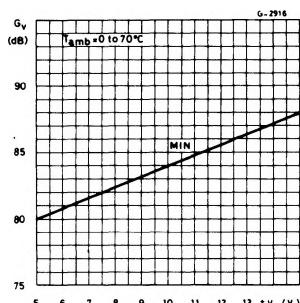


Fig. 15 - Voltage gain vs. supply voltage



TYPICAL APPLICATIONS

Fig. 16 - Inverting amplifier

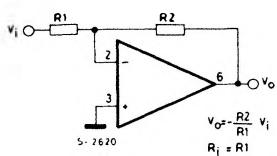


Fig. 17 - Non-inverting AC amplifier

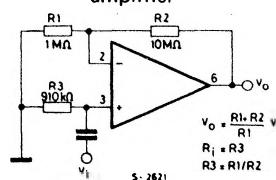


Fig. 18 - Non-inverting amplifier

